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Renesas Electronics website: <http://www.renesas.com>

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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H5N2801P

Silicon N Channel MOS FET
High Speed Power Switching

REJ03G0118-0100Z

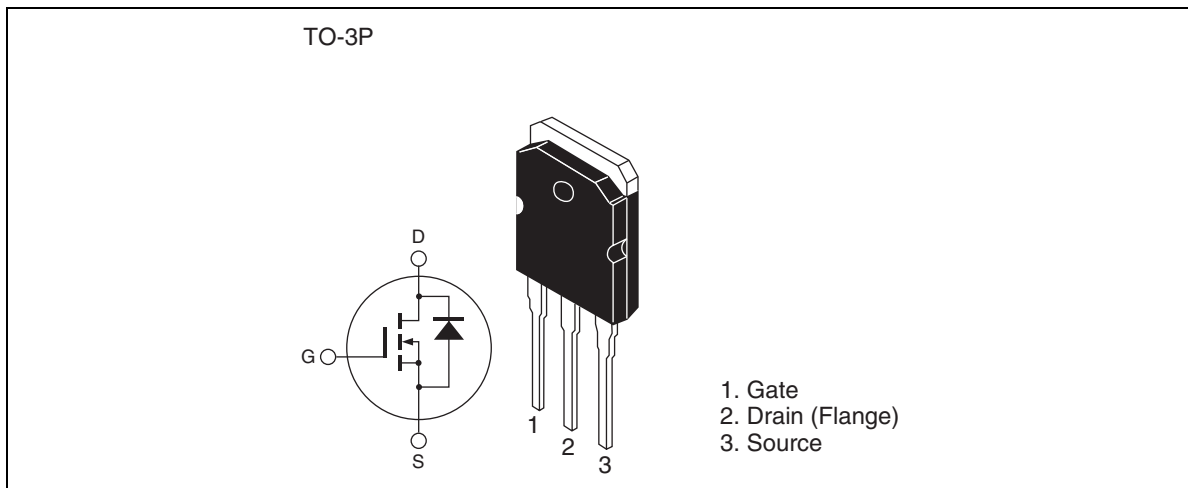
Rev.1.00

Oct.01.2003

Features

- Low on-resistance
- Low drive current
- High speed switching

Outline



Absolute Maximum Rating

(Ta = 25°C)

Item	Symbol	Rating	Unit
Drain to source voltage	V _{DSS}	280	V
Gate to source voltage	V _{GSS}	±30	V
Drain current	I _D	60	A
Drain peak current	I _{D (pulse)} ^{Note1}	240	A
Body-drain diode reverse drain current	I _{DR}	60	A
Avalanche current	I _{AP} ^{Note3}	35	A
Avalanche energy	E _{AR} ^{Note3}	74.5	mJ
Channel dissipation	P _{ch} ^{Note2}	150	W
Channel to case thermal impedance	θ _{ch-c}	0.833	°C /W
Channel temperature	T _{ch}	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

- Notes: 1. PW ≤ 10 μs, duty cycle ≤ 1%
2. Value at T_c = 25°C
3. ST_{ch} = 25°C, T_{ch} ≤ 150°C

H5N2801P

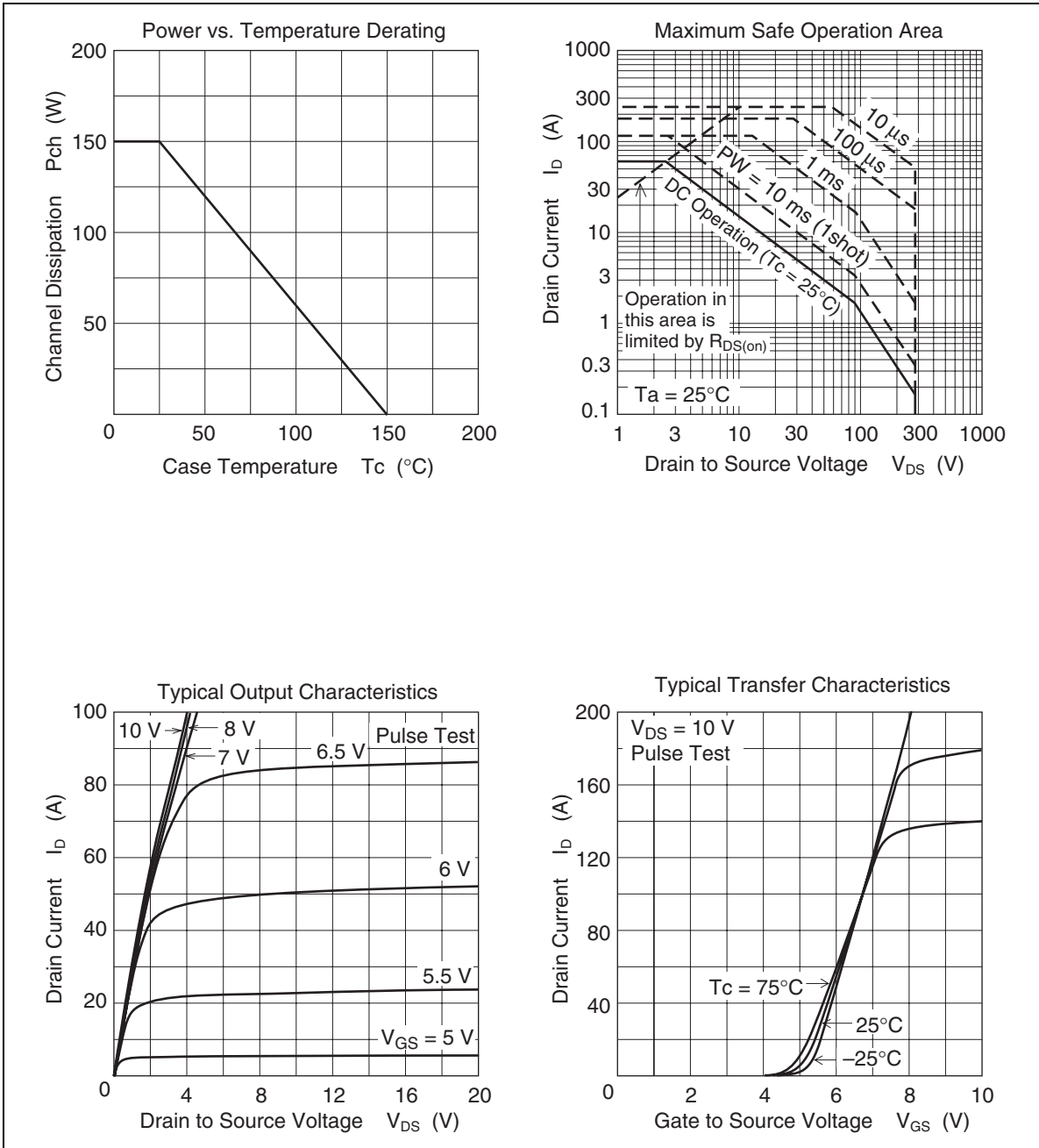
Electrical Characteristics

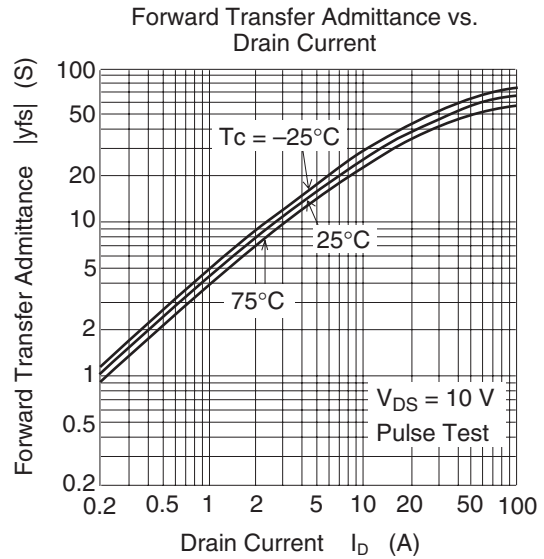
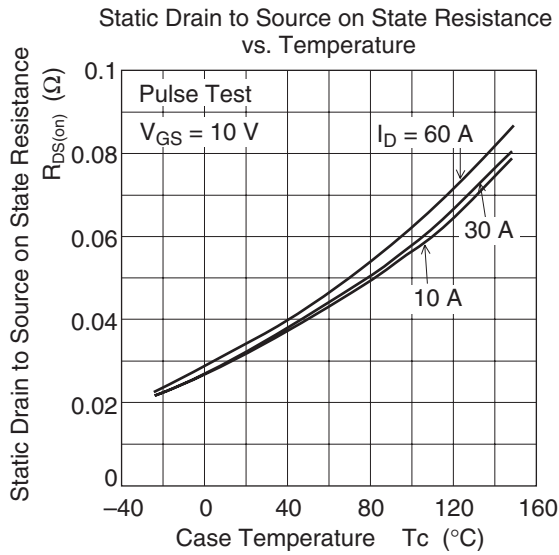
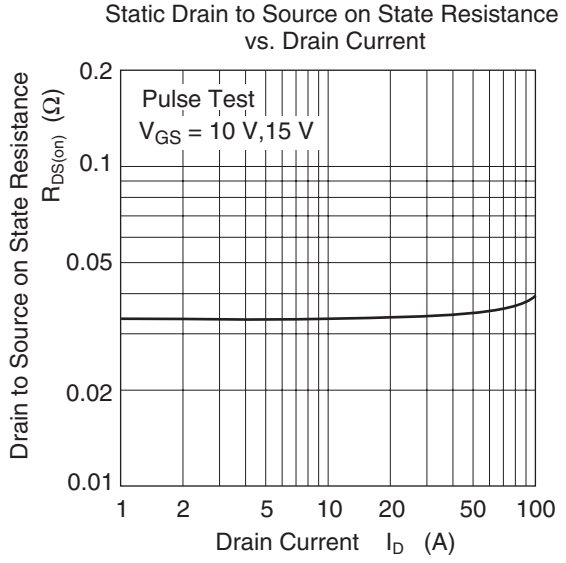
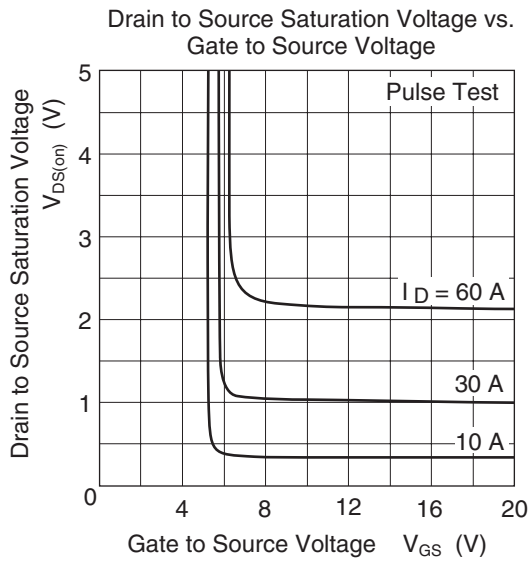
(T_a = 25°C)

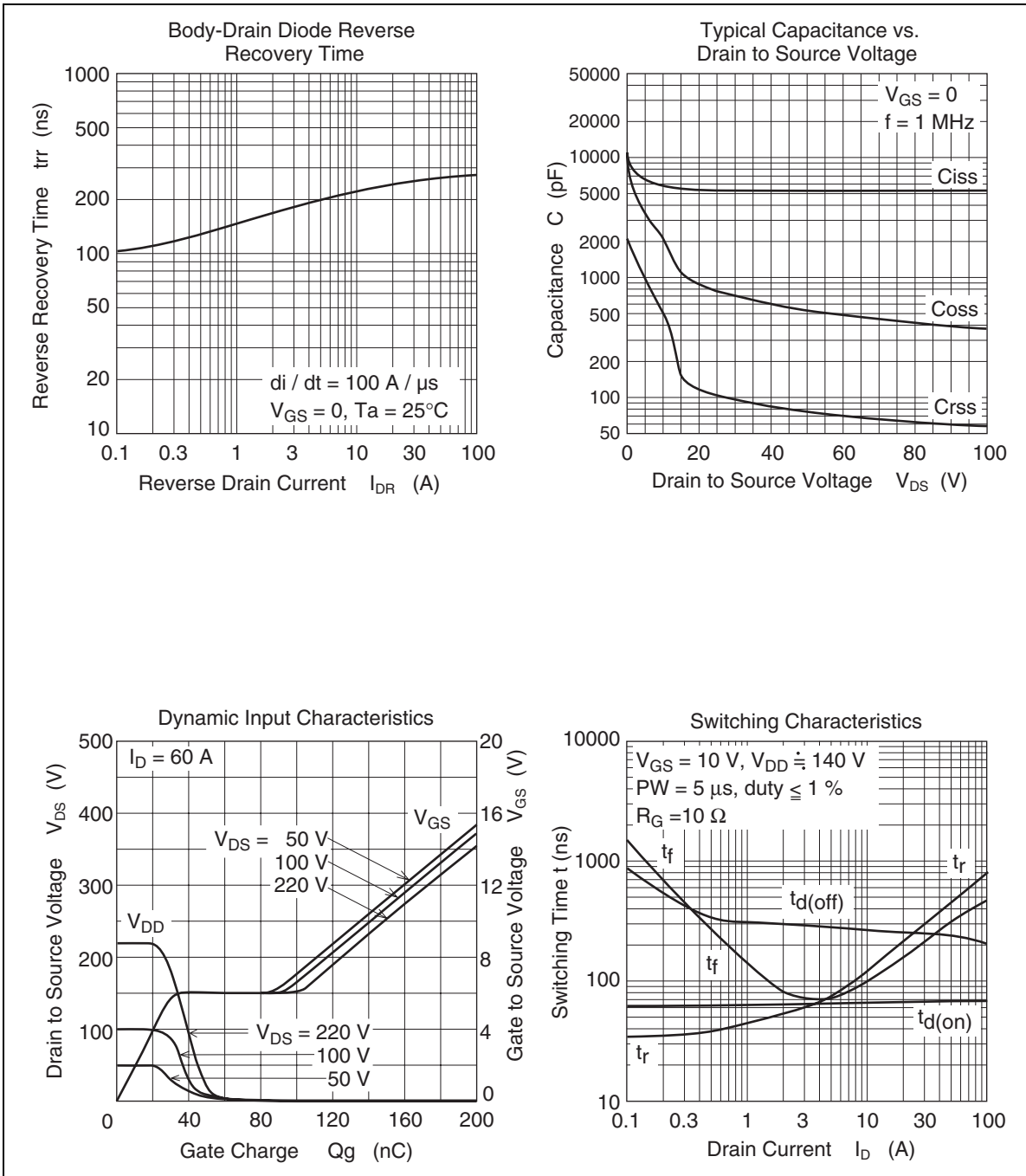
Item	Symbol	Min	Typ	Max	Unit	Test condition
Drain to Source breakdown voltage	V _{(BR)DSS}	280	—	—	V	I _D = 10 mA, V _{GS} = 0
Zero gate voltage drain current	I _{DSS}	—	—	1	μA	V _{DS} = 280 V, V _{GS} = 0
Gate to source leak current	I _{GSS}	—	—	±0.1	μA	V _{GS} = ±30 V, V _{DS} = 0
Gate to source cutoff voltage	V _{GS(off)}	3.0	—	4.5	V	V _{DS} = 10 V, I _D = 1 mA
Forward transfer admittance	y _{fs}	27	45	—	S	I _D = 30 A, V _{DS} = 10 V ^{Note4}
Static drain to source on state resistance	R _{DS(on)}	—	0.034	0.043	Ω	I _D = 30 A, V _{GS} = 10 V ^{Note4}
Input capacitance	C _{iss}	—	5400	—	pF	V _{DS} = 25 V
Output capacitance	C _{oss}	—	770	—	pF	V _{GS} = 0
Reverse transfer capacitance	C _{rss}	—	100	—	pF	f = 1 MHz
Turn-on delay time	t _{d(on)}	—	70	—	ns	I _D = 30 A
Rise time	t _r	—	300	—	ns	R _L = 4.7 Ω
Turn-off delay time	t _{d(off)}	—	250	—	ns	V _{GS} = 10 V
Fall time	t _f	—	210	—	ns	R _g = 10 Ω
Total gate charge	Q _g	—	148	—	nC	V _{DD} = 220 V
Gate to source charge	Q _{gs}	—	30	—	nC	V _{GS} = 10 V
Gate to drain charge	Q _{gd}	—	73	—	nC	I _D = 60 A
Body-drain diode forward voltage	V _{DF}	—	1.10	1.65	V	I _F = 60 A, V _{GS} = 0 ^{Note4}
Body-drain diode reverse recovery time	t _{rr}	—	270	—	ns	I _F = 60 A, V _{GS} = 0 diF/dt = 100 A/μs
Body-drain diode reverse recovery charge	Q _{rr}	—	2.8	—	μC	

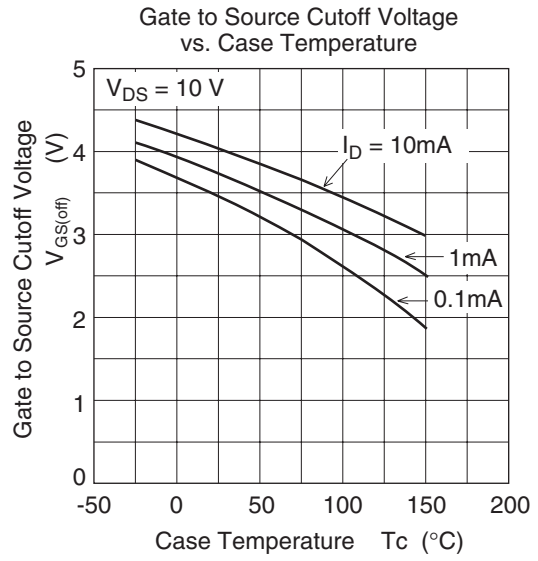
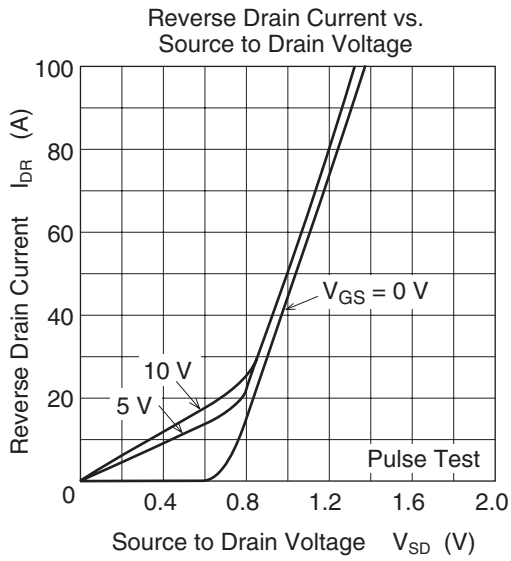
Notes: 4. Pulse test

Main Characteristics

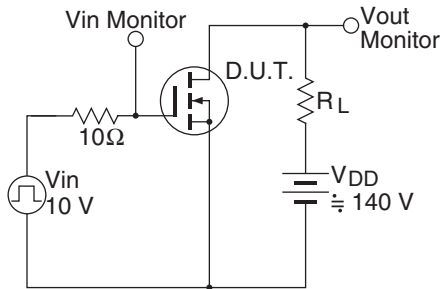




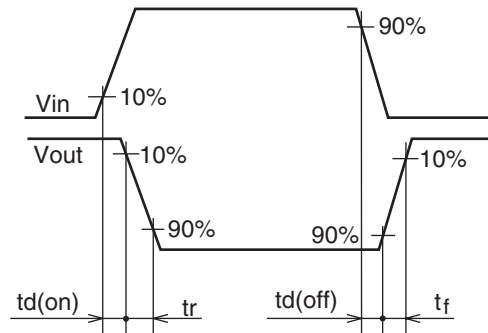


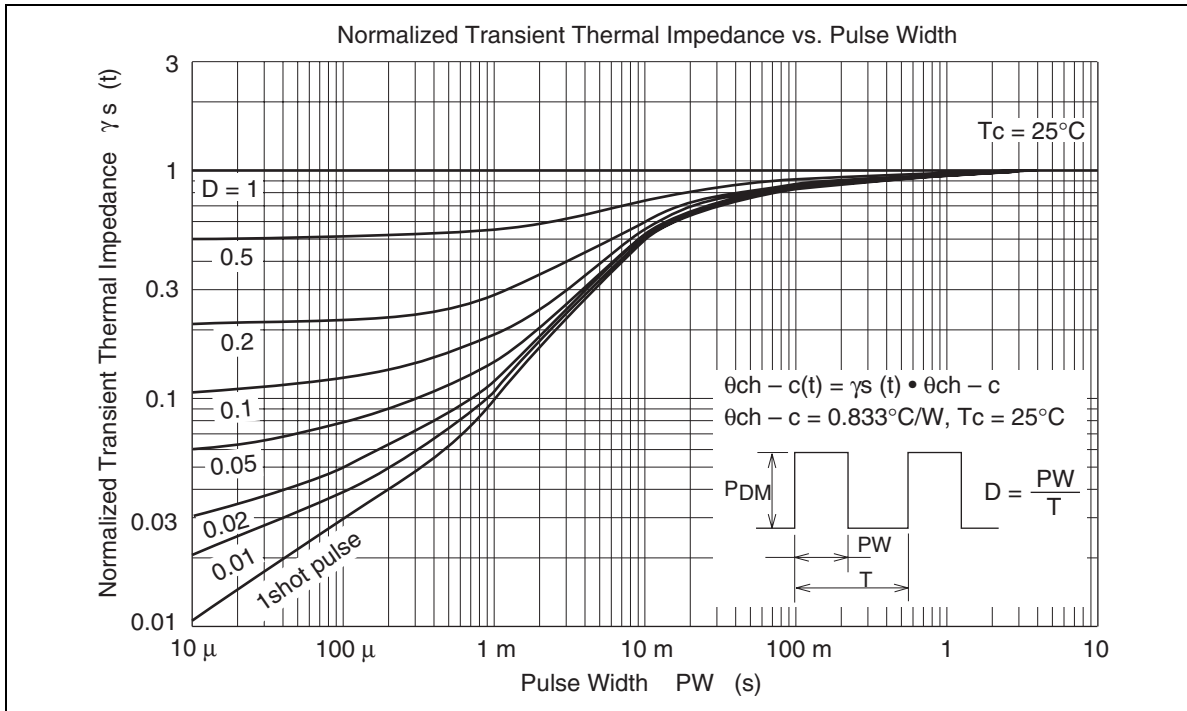


Switching Time Test Circuit

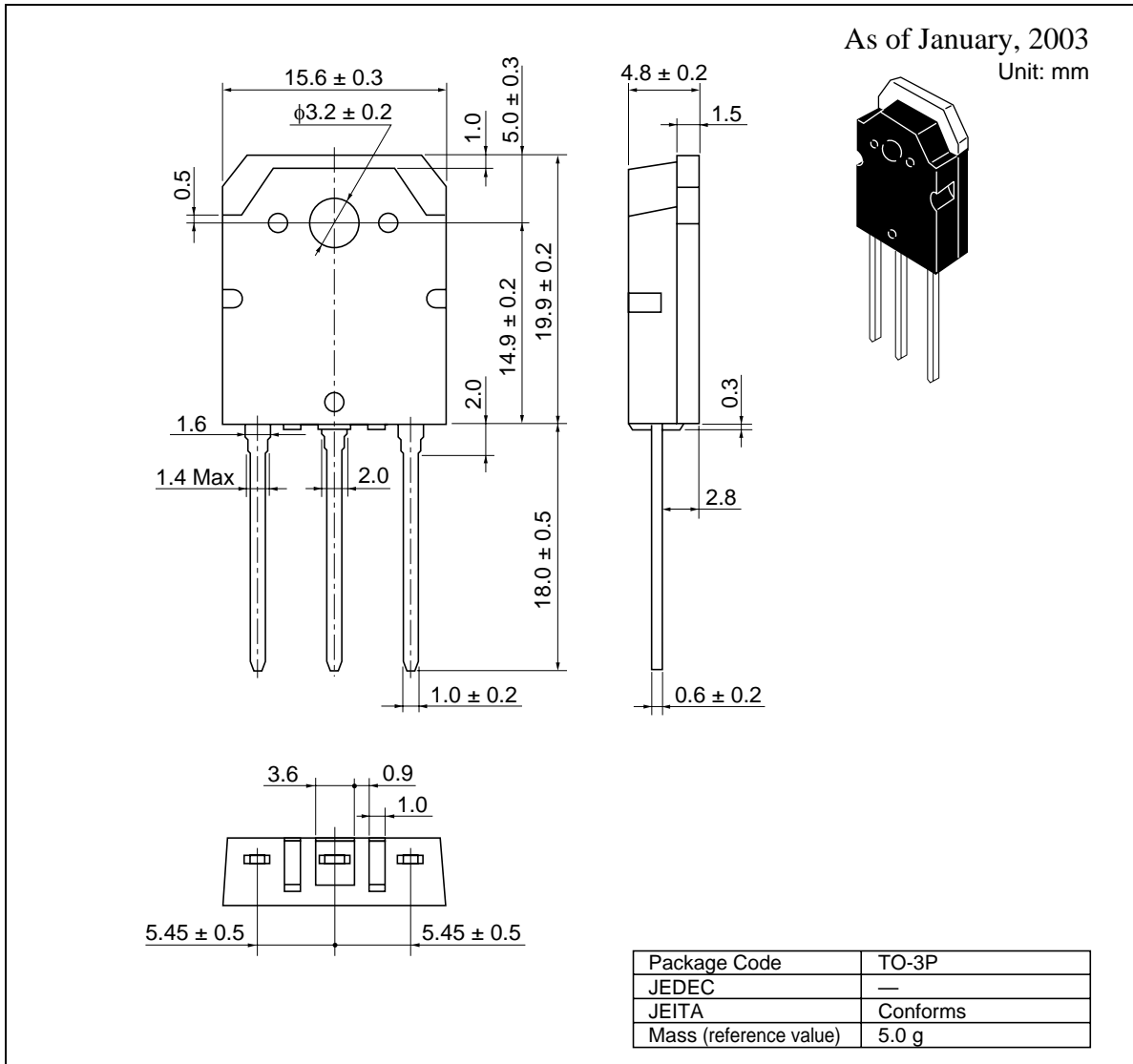


Waveform





Package Dimensions



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